



## ABSOLUTE MAXIMUM RATINGS (Note 1)

Input Voltage (+V <sub>IN</sub> ) .....	42V	Oscillator Charging Current .....	5mA
Collector Voltage .....	60V	Operating Junction Temperature	
Logic Inputs .....	-0.3V to 5.5V	Hermetic (J, L Packages) .....	150°C
Current Limit Sense Inputs .....	-0.3V to V <sub>IN</sub>	Plastic (N, DW Packages) .....	150°C
Output Current (each transistor) .....	200mA	Storage Temperature Range .....	-65°C to 150°C
Reference Load Current .....	50mA	Lead Temperature (Soldering, 10 seconds) .....	300°C

Note 1. Values beyond which damage may occur.

## THERMAL DATA

### J Package:

Thermal Resistance-Junction to Case, $\theta_{JC}$ .....	30°C/W
Thermal Resistance-Junction to Ambient, $\theta_{JA}$ .....	80°C/W

### N Package:

Thermal Resistance-Junction to Case, $\theta_{JC}$ .....	40°C/W
Thermal Resistance-Junction to Ambient, $\theta_{JA}$ .....	65°C/W

### DW Package:

Thermal Resistance-Junction to Case, $\theta_{JC}$ .....	40°C/W
Thermal Resistance-Junction to Ambient, $\theta_{JA}$ .....	95°C/W

### L Package:

Thermal Resistance-Junction to Case, $\theta_{JC}$ .....	35°C/W
Thermal Resistance-Junction to Ambient, $\theta_{JA}$ .....	120°C/W

Note A. Junction Temperature Calculation:  $T_J = T_A + (P_D \times \theta_{JA})$ .

Note B. The above numbers for  $\theta_{JC}$  are maximums for the limiting thermal resistance of the package in a standard mounting configuration. The  $\theta_{JA}$  numbers are meant to be guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.

## RECOMMENDED OPERATING CONDITIONS (Note 2)

Input Voltage (+V <sub>IN</sub> ) .....	7V to 40V	Oscillator Frequency Range .....	100Hz to 400KHz
Collector Voltage .....	0V to 60V	Oscillator Timing Resistor (R <sub>T</sub> ) .....	2K $\Omega$ to 150K $\Omega$
Error Amp Common Mode Range .....	2.3V to V <sub>REF</sub>	Oscillator Timing Capacitor (C <sub>T</sub> ) .....	1nF to 0.1 $\mu$ F
Current Limit Sense Common Mode Range .....	0V to V <sub>IN</sub> -2.5V	Operating Ambient Temperature Range	
Output Current (each transistor) .....	0 to 100mA	SG1524B .....	-55°C to 125°C
Reference Load Current .....	0 to 20mA	SG2524B .....	-25°C to 85°C
Oscillator Charging Current .....	25 $\mu$ A to 1.8mA	SG3524B .....	0°C to 70°C

Note 2: Range over which the device is functional.

## ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, these specifications apply over the operating ambient temperatures for SG1524B with -55°C ≤ T<sub>A</sub> ≤ 125°C, SG2524B with -25°C ≤ T<sub>A</sub> ≤ 85°C, SG3524B with 0°C ≤ T<sub>A</sub> ≤ 70°C, and +V<sub>IN</sub> = 20V. Low duty cycle pulse testing techniques are used which maintains junction and case temperatures equal to the ambient temperature.)

Parameter	Test Conditions	SG1524B/2524B			SG3524B			Units
		Min.	Typ.	Max.	Min.	Typ.	Max.	
<b>Reference Section (Note 3)</b>								
Output Voltage	T <sub>J</sub> = 25°C	4.95	5.00	5.05	4.90	5.00	5.10	V
Line Regulation	V <sub>IN</sub> = 7V to 40V		3	20		3	30	mV
Load Regulation	I <sub>L</sub> = 0 to 20mA		5	30		5	50	mV
Temperature Stability (Note 7)	Over Operating Temperature Range		15	50		15	50	mV
Total Output Voltage Range	Over Line, Load and Temperature	4.90		5.10	4.80		5.20	V
Short Circuit Current	V <sub>REF</sub> = 0V	25	50	120	25	50	120	mA
<b>Undervoltage Lockout Section</b>								
Threshold Voltage		4.3	4.5	4.7	4.2	4.5	4.9	V

Note 3. I<sub>L</sub> = 0mA

## ELECTRICAL CHARACTERISTICS (continued)

Parameter	Test Conditions	SG1524B/2524B			SG3524B			Units
		Min.	Typ.	Max.	Min.	Typ.	Max.	
<b>Oscillator Section</b> (Note 4)								
Initial Accuracy	$T_J = 25^\circ\text{C}$	42	45	48	40	45	50	KHz
Voltage Stability	$V_{IN} = 7\text{V to }40\text{V}$		0.1	1		0.1	1	%
Temperature Stability (Note 7)	Over Operating Range		1	2		1	2	%
Minimum Frequency (Note 7)	$R_T = 150\text{K}\Omega, C_T = 0.1\mu\text{F}$		50	140		50	120	Hz
Maximum Frequency	$R_T = 2\text{K}\Omega, C_T = 470\text{pF}$	400	600		400	600		KHz
Sawtooth Peak Voltage	$V_{IN} = 40\text{V}$		3.5	3.9		3.5	3.9	V
Sawtooth Valley Voltage	$V_{IN} = 7\text{V}$	0.6	1		0.6	1		V
Clock Amplitude		3.0	4.0		3.0	4.0		V
Clock Pulse Width		0.2	0.5	1.2	0.2	0.5	1.2	$\mu\text{s}$
<b>Error Amplifier Section</b> (Note 5)								
Input Offset Voltage	$R_S \leq 2\text{K}\Omega$		0.5	5		2	10	mV
Input Bias Current			1	5		1	10	$\mu\text{A}$
Input Offset Current				1			1	$\mu\text{A}$
DC Open Loop Gain	$R_L \geq 10\text{M}\Omega$	60	78		60	78		dB
Output Low Level	$I_{\text{SINK}} = 100\mu\text{A}; V_{\text{PIN}1} - V_{\text{PIN}2} \geq 150\text{mV}$		0.2	0.5		0.2	0.5	V
Output High Level	$I_{\text{SOURCE}} = 100\mu\text{A}; V_{\text{PIN}2} - V_{\text{PIN}1} \geq 150\text{mV}$	3.8	4.2		3.8	4.2		V
Common Mode Rejection	$V_{\text{CM}} = 2.3\text{V to }V_{\text{REF}}$	70	90		70	90		dB
Supply Voltage Rejection	$V_{IN} = 7\text{V to }40\text{V}$	76	100		76	100		dB
Gain-Bandwidth Product (Note 7)	$T_J = 25^\circ\text{C}$	1	2		1	2		MHz
<b>P.W.M. Comparator</b> (Note 4)								
Minimum Duty Cycle	$V_{\text{COMP}} = 0.5\text{V}$			0			0	%
Maximum Duty Cycle	$V_{\text{COMP}} = 3.9\text{V}$	45	49		45	49		%
<b>Current Limit Amplifier Section</b> (Note 6)								
Sense Voltage		180	200	220	170	200	230	mV
Input Bias Current			-3	-10		-3	-10	$\mu\text{A}$
<b>Shutdown Input Section</b>								
HIGH Input Voltage		2.0			2.0			V
HIGH Input Current	$V_{\text{SHUTDOWN}} = 5.0\text{V}$		0.1	1		0.1	1	mA
LOW Input Voltage				0.6			0.6	V
<b>Output Section</b> (each transistor)								
Collector Leakage Current	$V_{\text{CE}} = 60\text{V}$			50			50	$\mu\text{A}$
Collector Saturation Voltage	$I_C = 10\text{mA}$		0.2	0.4		0.2	0.4	V
	$I_C = 100\text{mA}$		1.0	2.0		1.0	2.0	V
Emitter Output Voltage	$I_E = 10\text{mA}$	17.5	19		17.5	19		V
	$I_E = 100\text{mA}$	17	18		17	18		V
Emitter Voltage Rise Time (Note 7)	$R_E = 2\text{K}\Omega, T_A = 25^\circ\text{C}$		0.2	0.5		0.2	0.5	$\mu\text{s}$
Collector Voltage Fall Time	$R_C = 2\text{K}\Omega, T_A = 25^\circ\text{C}$		0.1	0.2		0.1	0.2	$\mu\text{s}$
<b>Power Consumption</b>								
Standby Current	$V_{IN} = 40\text{V}, V_{\text{SHUTDOWN}} = 2.0\text{V}$		5	12		5	12	mA

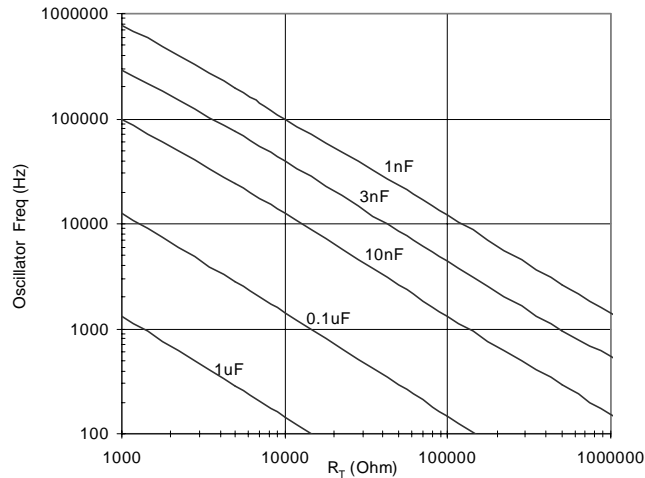
Note 4.  $F_{\text{OSC}} = 45\text{KHz}$  ( $R_T = 2700\Omega, C_T = .01\mu\text{F}$ )

Note 5.  $V_{\text{CM}} = 2.3\text{V to }V_{\text{REF}}$

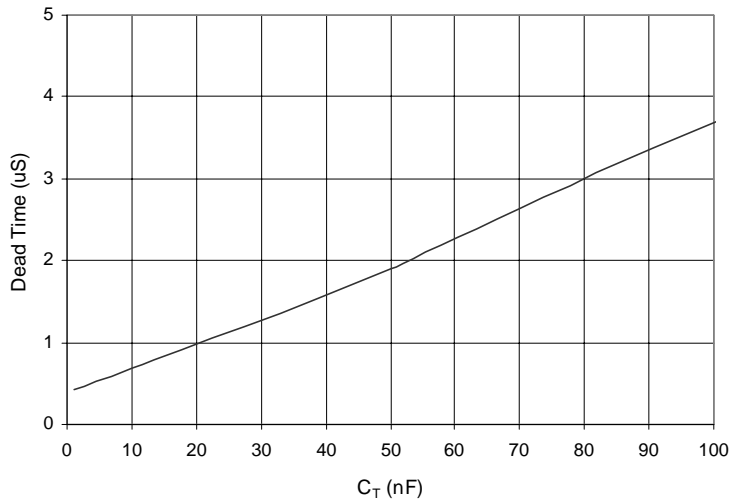
Note 6.  $V_{\text{CM}} = 0\text{V to }17.5\text{V}$

Note 7. These parameters, although guaranteed over the recommended operating conditions, are not tested in production.

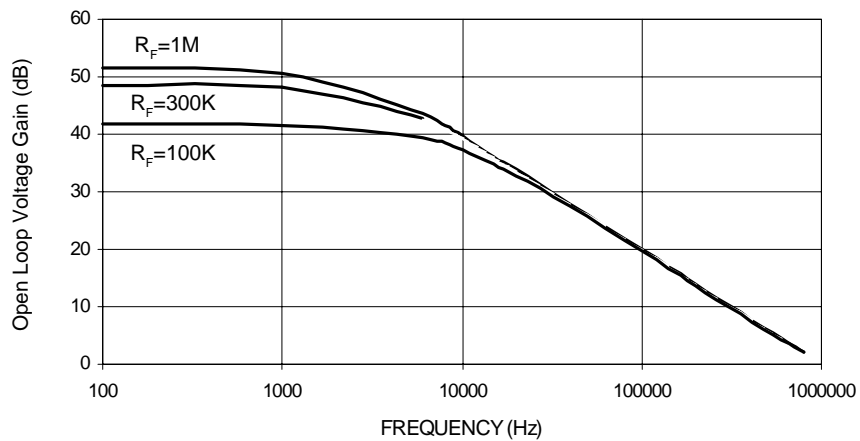
TYPICAL CHARACTERISTIC CURVES



**Figure 1**  
Oscillator Frequency vs. Timing Resistor and Capacitor  
 $V_{IN}=20V, T_A=25^{\circ}C$



**Figure 2**  
SG1524B Dead Time vs. Timing capacitance ( $R_T=2.7k$ )  
 $V_{IN}=20V, T_A=25^{\circ}C$



**Figure 3**  
SG1524B Error Amp Voltage Gain vs. Freq over  $R_F$   
 $V_{IN}=20V, T_A=25^{\circ}C$

# SG1524B/SG2524B/SG3524B

## CONNECTION DIAGRAMS & ORDERING INFORMATION (See Notes Below)

Package	Part No.	Ambient Temperature Range	Connection Diagram
16-PIN CERAMIC DIP J - PACKAGE	SG1524BJ/883B SG1524BJ/DESC	-55°C to 125°C	
16-PIN PLASTIC DIP N - PACKAGE	SG2524BJ SG3524BJ	-55°C to 125°C -25°C to 85°C 0°C to 70°C	
16-PIN PLASTIC DIP N - PACKAGE	SG2524BN SG3524BN	-25°C to 85°C 0°C to 70°C	
16-PIN WIDE BODY PLASTIC S.O.I.C. DW - PACKAGE	SG2524BDW SG3524BDW	-25°C to 85°C 0°C to 70°C	
20-PIN CERAMIC LEADLESS CHIP CARRIER L - PACKAGE	SG1524BL/883B SG1524BL	-55°C to 125°C -55°C to 125°C	

Note 1. Contact factory for JAN and DESC product availability.  
2. All packages are viewed from the top.